

### **High-Voltage Switchmode Regulator**

#### FEATURES

- 10- to 120-V Input Range
- Current-Mode Control
- On-Chip 200-V, 5-Ω MOSFET Switch
  Internal Start-Up Circuit
- SHUTDOWN and RESET

High Efficiency Operation (>80%)

Internal Oscillator (1 MHz)

#### DESCRIPTION

The Si9104 high-voltage switchmode regulator is a monolithic BiC/DMOS integrated circuit which contains most of the components necessary to implement a high-efficiency dc-to-dc converter up to 3 watts. It can either be operated from a low-voltage dc supply, or directly from a 10- to 120-V unregulated dc power source.

This device may be used with an appropriate transformer to implement most single-ended isolated power converter topologies (i.e., flyback and forward).

The Si9104 is available in a 16-pin wide-body SOIC and is specified over the D suffix (-40 to 85°C) temperature range.

# FUNCTIONAL BLOCK DIAGRAM



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#### **ABSOLUTE MAXIMUM RATINGS**

Valtanaa	Defensed	4- X/	A. (		0 0 1 //
voltages	Referenced	το - V <sub>IN</sub>	$(V_{CC} <$	$+V_{IN} +$	0.3 V)

Ū		00		,	
V <sub>CC</sub>					15 V
+V <sub>IN</sub>					120 V
V <sub>DS</sub>					200 V
$I_D$ (Peak) (300 $\mu$ s pulse, 2	2% d	uty cy	cle)		2 A
I <sub>D</sub> (rms)					250 mA
Logic Inputs (RESET, SH	UTD	OWN,	OSC IN)	0.3 V	to V <sub>CC</sub> + 0.3 V
Linear Inputs (FEEDBAC	K, S0	OURC	E)		0.3 V to 7 V
HV Pre-Regulator Input (	Curre	nt (coi	ntinuous)		3 mA
Storage Temperature					65 to 125°C

Operating Temperature40 to 85°C
Junction Temperature $(T_J),\ldots,\ldots,\ldots,150^\circ C$
Power Dissipation (Package) <sup>a</sup>
16-Pin Plastic Wide-Body SOIC <sup>b</sup> 900 mW
Thermal Impedance ( $\Theta_{JA}$ )
16-Pin Plastic Wide-Body SOIC140°C/W
Notes
a. Device mounted with all leads soldered or welded to PC board.

b. Derate 7.2 mW/°C above 25°C.

#### **RECOMMENDED OPERATING RANGE**

Voltages Referenced to -VIN

V <sub>CC</sub>		 				 									10	V	to	13.	5 V
+V <sub>IN</sub>		 				 									10	٥N	/ to	12	0 V
f <sub>OSC</sub>		 				 								40	) k	Hz	to	1 N	1Hz

R <sub>OSC</sub>	 $\ldots \ldots \ldots \ldots .25$ k $\Omega$ to 1 M $\Omega$
Linear Inputs	 0 to 7 V
Digital Inputs	 0 to V <sub>CC</sub>

SPECIFICATIONS <sup>a</sup>									
		Test Conditions Unless Otherwise Specified	[						
Parameter	Symbol	$\begin{aligned} \text{DISCHARGE} &= -\text{V}_{\text{IN}} = 0 \text{ V},  \text{V}_{\text{CC}} = 10 \text{ V} \\ +\text{V}_{\text{IN}} &= 48 \text{ V},  \text{R}_{\text{BIAS}} = 390  \text{k} \Omega \\ \text{R}_{\text{OSC}} &= 330  \text{k} \Omega \end{aligned}$	Temp <sup>b</sup>	<b>Min</b> <sup>d</sup>	Тур <sup>с</sup>	Max <sup>d</sup>	Unit		
Reference			_	_	_				
Output Voltage	V <sub>R</sub>	OSC IN = - $V_{IN}$ (OSC Disabled) R <sub>L</sub> = 10 MΩ	Room Full	3.92 3.85	4.0	4.08 4.15	V		
Output Impedance <sup>e</sup>	Z <sub>OUT</sub>		Room	15	30	45	kΩ		
Short Circuit Current	I <sub>SREF</sub>	$V_{REF} = -V_{IN}$	Room	70	100	130	μΑ		
Temperature Stability <sup>e</sup>	т		Full		0.25	1.0	mV/°C		
Long Term Stability <sup>e</sup>	'REF	t = 1000 hrs., T <sub>A</sub> = 125°C	Room		5	25	mV		
Oscillator									
Maximum Frequency <sup>e</sup>	f <sub>MAX</sub>	$R_{OSC} = 0$	Room	1	3		MHz		
	¢	$R_{OSC} = 330 \text{ k}\Omega^{f}$	Room	80	100	120	ki iz		
Initial Accuracy	IOSC	$R_{OSC} = 150 \text{ k}\Omega^{\text{f}}$	Room	160	200	240	КПД		
Voltage Stability	∆f/f	$\Delta f/f = f(13.5 \text{ V}) - f(10 \text{ V}) / f(10 \text{ V})$	Room	4	10	15	%		
Temperature Coefficient <sup>e</sup>	T <sub>OSC</sub>		Full		200	500	ppm/ °C		
Error Amplifier									
Feedback Input Voltage	V <sub>FB</sub>	FB Tied to COMP OSC IN = - V <sub>IN</sub> (OSC Disabled)	Room	3.96	4.00	4.04	V		
Input BIAS Current	I <sub>FB</sub>	OSC IN = - $V_{IN}$ , $V_{FB}$ = 4 V	Room		25	500	nA		
Input OFFSET Voltage	V <sub>OS</sub>		Room		±15	±40	mV		
Open Loop Voltage Gain <sup>e</sup>	A <sub>VOL</sub>		Room	60	80		dB		
Unity Gain Bandwidth <sup>e</sup>	BW	$OSC IN = - v_{IN} (OSC Disabled)$	Room	0.7	1		MHz		
Dynamic Output Impedance <sup>e</sup>	Z <sub>OUT</sub>		Room		1000	2000	Ω		
Output Current	1	Source (V <sub>FB</sub> = 3.4 V)	Room		-2.0	-1.4	m ^		
	OUT	Sink (V <sub>FB</sub> = 4.5 V)	Room	0.12	0.15		mA		
Power Supply Rejection	PSRR	$10~\text{V} \leq \text{V}_{\text{CC}} \leq 13.5~\text{V}$	Room	50	70		dB		



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<b>SPECIFICATIONS</b> <sup>a</sup>							
		Test Conditions Unless Otherwise Specified	[				
Parameter	Symbol	$+V_{IN} = 48 \text{ V},  \text{R}_{\text{BIAS}} = 390  \text{k}\Omega$ $R_{\text{OSC}} = 330  \text{k}\Omega$	Temp <sup>b</sup>	Temp <sup>b</sup> Min <sup>d</sup> Typ			Unit
Current Limit							
Threshold Voltage	V <sub>SOURCE</sub>	$\rm R_L$ = 100 $\Omega$ from DRAIN to V <sub>CC,</sub> $\rm V_{FB}$ = 0 V	Room	1.0	1.2	1.4	V
Delay to Output	t <sub>d</sub>	$R_L$ = 100 Ω from DRAIN to V <sub>CC</sub> V <sub>SOURCE</sub> = 1.5 V, See Figure 1.	Room		100	200	ns
Pre-Regulator/Start-Up							
Input Voltage	+V <sub>IN</sub>	I <sub>IN</sub> = 10 μA	Room	120			V
Input Leakage Current	+I <sub>IN</sub>	$V_{CC} \ge 10 V$	Room			10	μA
Pre-Regulator Start-Up Current	I <sub>START</sub>	Pulse Width $\leq$ 300 $\mu s,~V_{CC}$ = 7 V	Room	8	15		mA
V <sub>CC</sub> Pre-Regulator Turn-Off Threshold Voltage	V <sub>REG</sub>	I <sub>PRE-REGULATOR</sub> = 10 μA	Room	7.8	9.4	9.8	
Undervoltage Lockout	V <sub>UVLO</sub>	$R_L = 100 \Omega$ from DRAIN to V <sub>CC</sub> See Detailed Description	Room	7.0	8.8	9.3	V
V <sub>REG</sub> - V <sub>UVLO</sub>	V <sub>DELTA</sub>		Room	0.3	0.6		
Supply							
Supply Current	I <sub>CC</sub>		Room	0.45	0.6	1.0	mA
Bias Current	I <sub>BIAS</sub>		Room	10	15	20	μA
Logic	-		_	-	_	-	
SHUTDOWN Delay <sup>e</sup>	t <sub>SD</sub>	$V_{SOURCE} = -V_{IN}$ , See Figure 2.	Room		50	100	
SHUTDOWN Pulse Width <sup>e</sup>	t <sub>SW</sub>		Room	50			
RESET Pulse Width <sup>e</sup>	t <sub>RW</sub>		Room	50			ns
Latching Pulse Width <sup>e</sup> SHUTDOWN and RESET Low	t <sub>LW</sub>	See Figure 3.	Room	25			
Input Low Voltage	V <sub>IL</sub>		Room			2.0	V
Input High Voltage	V <sub>IH</sub>		Room	8.0			v
Input Current Input Voltage High	I <sub>IH</sub>	V <sub>IN</sub> = V <sub>CC</sub>	Room		1	5	
Input Current Input Voltage Low	I <sub>IL</sub>	V <sub>IN</sub> = 0 V	Room	-35	-25		μΑ
MOSFET Switch							
Breakdown Voltage	V <sub>BR(DSS)</sub>	I <sub>DRAIN</sub> = 100 μA	Full	200	220		V
Drain-Source On-Resistance <sup>g</sup>	r <sub>DS(on)</sub>	I <sub>DRAIN</sub> = 100 mA	Room		3	5	Ω
Drain Off Leakage Current	I <sub>DSS</sub>	V <sub>DRAIN</sub> = 150 V	Room		5	10	μA
Drain Capacitance <sup>e</sup>	C <sub>DS</sub>		Room		35		pF

Notes

a. Refer to PROCESS OPTION FLOWCHART for additional information.

b. Room = 25°C, Cold and Hot = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

f. C<sub>STRAY</sub> @ OSC IN  $\leq$  5 pF.

g. Temperature coefficient of  $r_{DS(on)}$  is 0.75% per °C, typical.

### Si9104

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#### **TIMING WAVEFORMS**



FIGURE 3.

#### **TYPICAL CHARACTERISTICS**



FIGURE 4.

(TH) 100 k 10 k

100 k

 $r_{OSC}$  - Oscillator Resistance ( $\Omega$ )

#### FIGURE 5.

10 k

#### S-60752—Rev. E, 05-Apr-99 4

1 M



#### **PIN CONFIGURATIONS**



Top View Order Number: Si9104DW

PIN DESCRIPTION										
	Pin Number									
Function	14-Pin Plastic DIP	16-Pin SOIC	20-Pin PLCC							
SOURCE	4	1	7							
-V <sub>IN</sub>	5	2	8							
V <sub>CC</sub>	6	4	9							
OSC <sub>OUT</sub>	7	5	10							
OSC <sub>IN</sub>	8	6	11							
DISCHARGE	9	7	12							
V <sub>REF</sub>	10	8	14							
SHUTDOWN	11	9	16							
RESET	12	10	17							
COMP	13	11	18							
FB	14	12	20							
BIAS	1	13	2							
+V <sub>IN</sub>	2	14	3							
DRAIN	3	16	5							
NC		3, 15	1, 4, 6, 13, 15, 19							

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### SOIC (WIDE-BODY): 16-LEAD (POWER IC ONLY)



ECN: S-40079—Rev. A, 02-Feb-04 DWG: 5910



DETAIL A





All Dimensions In Inches



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